



SLS SEMICONDUCTOR (SHENZHEN) CO.,LTD.

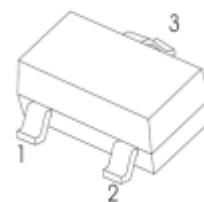
SOT-23 封装半导体二极管/SOT-23 Plastic-Encapsulate Diodes

MMBD4148A/CA/CC/SE (SWITCHING DIODES)

特点/Features :

速度快；
反向阻抗高；

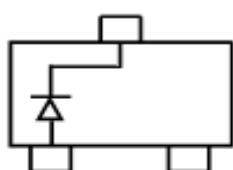
SOT-23



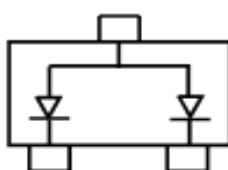
用途/Applications :

高速开关电路。

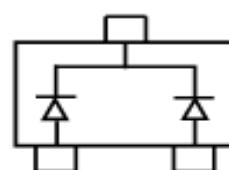
电路和印章/Circuit&Marking:



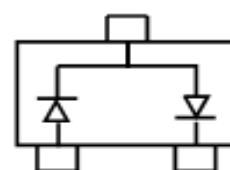
MMBD4148A
MARKING : 5H



MMBD4148CA
MARKING : D6



MMBD4148CC
MARKING : D5



MMBD4148SE
MARKING : D4

极限参数/Absolute maximum ratings(Ta=25°C)

| 参数/Parameter | 符号/ Symbol | 数值/Value | 单位/Unit |
|---|-----------------|------------|---------|
| 反向直流电压/DC Reverse Voltage | V_R | 100 | V |
| 反向重复峰值电压/Peak Repetitive Reverse Voltage | V_{RRM} | | |
| 正向连续电流/Forward Continuous Current | I_{FM} | 300 | mA |
| 平均整流输出电流/Average Rectified Output Current | I_0 | 200 | mA |
| 正向瞬间峰值电流 @=1μS Peak Forward Surge Current @=1.0S | $I_{FM(surge)}$ | 2.0 1.0 | A |
| 功率/ Power Dissipation | P_D | 0.35 | W |
| 热阻/Thermal Resistance Junction to Ambient Air | $R_{\theta JA}$ | 357 | °C/W |
| 结温/Junction Temperature | T_j | 150 | °C |
| 储存温度/Storage Temperature | T_{stg} | -55~150 | °C |

电性能参数/Electrical characteristics (Ta=25°C)

| 参数/Parameter | 符号 | 测试条件 | 最小值 | 最大值 | 单位 |
|--------------------------------------|--------------|--|-----|-----|---------|
| 反向击穿电压 Reverse Breakdown Voltage | $V_{BR(R1)}$ | $I_R=100 \mu A$ | 100 | | V |
| | $V_{BR(R2)}$ | $I_R=5 \mu A$ | 75 | | V |
| 正向电压/Forward Voltage | V_{F1} | $I_F=10mA$ | | 1 | V |
| 反向漏电流/Reverse Current | I_{R1} | $V_R=75V$ | | 5 | μA |
| | I_{R2} | $V_R=25V$ | | 25 | nA |
| 端电容 Capacitance Between Terminals | C_T | $V_R=0, f=1MHz$ | | 4 | pF |
| 反向恢复时间 Reverse Recovery Time | t_{rr} | $I_F=I_R=10mA, V_R=6V,$ $I_{rr}=0.1 \times I_R, R_L=100 \Omega$ | | 4 | nS |



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典型特性曲线图/Typical Characteristics

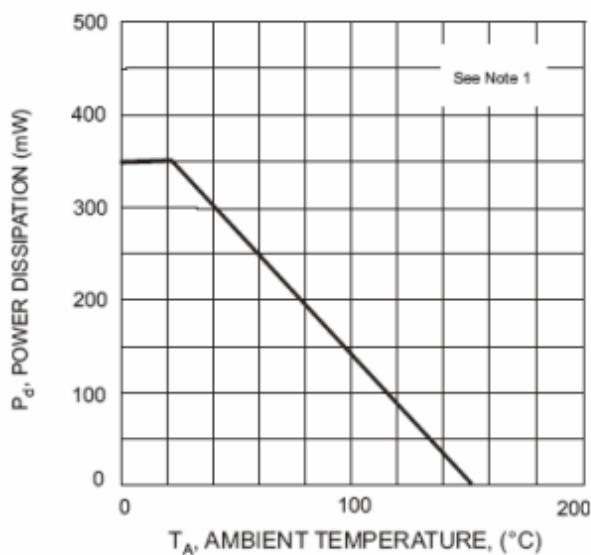


Fig. 1 Power Derating Curve

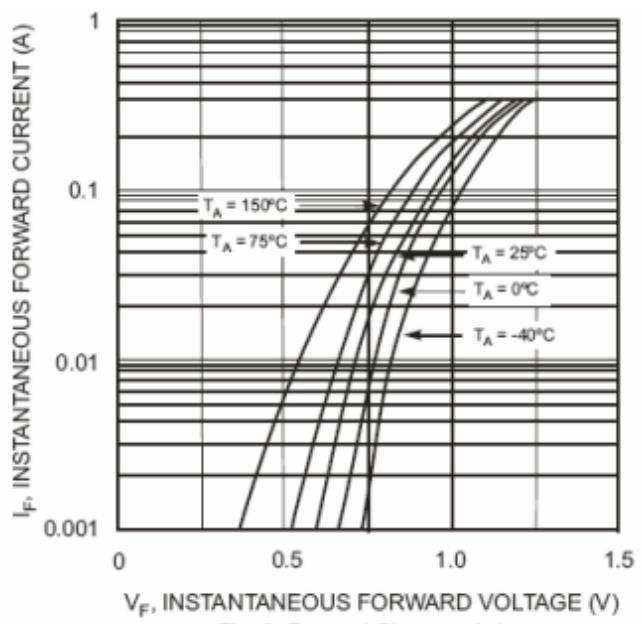


Fig. 2 Forward Characteristics

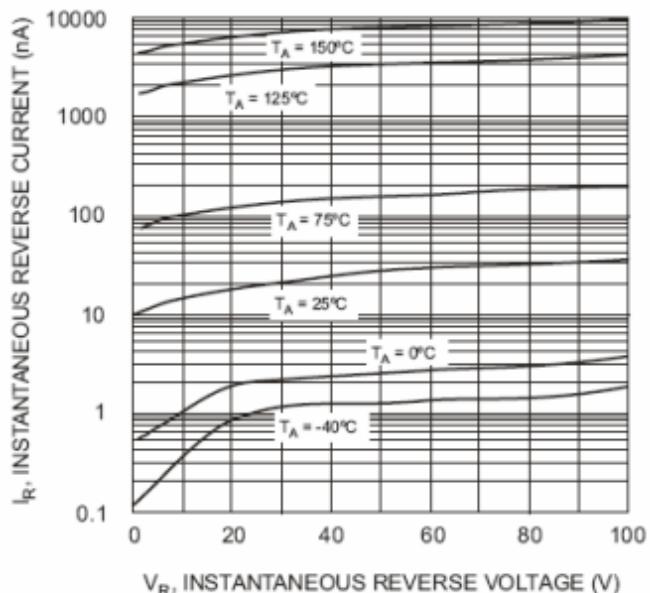


Fig. 3 Typical Reverse Characteristics

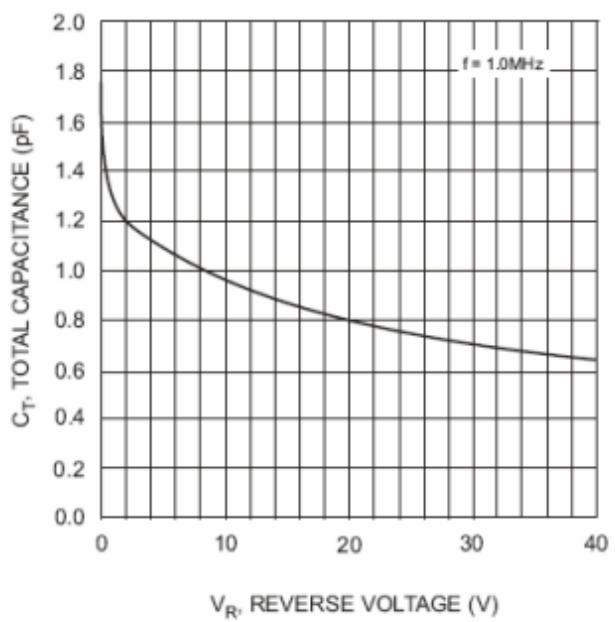


Fig. 4 Typical Capacitance vs. Reverse Voltage